

HIGH DENSITY MOUNTING ACINPUT, PHOTOTRANSISTOR OPTICALLY COUPLED ISOLATORS



DESCRIPTION

The IS126 is an optically coupled isolator consisting of two infrared light emitting diodes connected in inverse parallel and NPN silicon photo transistor in a space efficient dual in line plastic package.

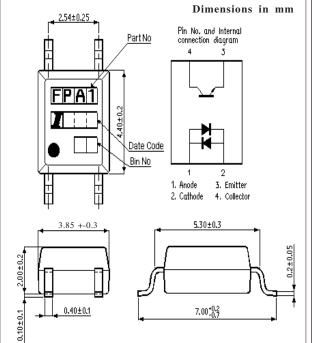
FEATURES

- Marked as FPA1.
- Current Transfer Ratio MIN. 20%
- $\begin{array}{l} \mbox{Isolation Voltage} (3.75 kV_{\mbox{\tiny RMS}}, \!\! 5.3 kV_{\mbox{\tiny PK}}) \\ \mbox{All electrical parameters} 100\% \mbox{ tested} \end{array}$
- Drop in replacement for Toshiba TLP126

APPLICATIONS

- Computer terminals
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and

impedances



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ABSOLUTEMAXIMUMRATINGS (25°C unless otherwise specified)

Storage Temperature	55°Cto+150°C
Operating Temperature	55°Cto+100°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for	10 secs) 260°C

INPUTDIODE

Forward Current	±50mA
Power Dissipation	 70mW

OUTPUTTRANSISTOR

Collector-emitter Voltage BV _{CEO}	35V
Emitter-collector Voltage BV _{ECO}	6V
Collector Current	50mA
Power Dissipation	150mW

POWERDISSIPATION

Total Power Dissipation	170mW
(derate linearly 2.26mW/°C above 25°C)	

ELECTRICAL CHARACTERISTICS ($\rm T_{A}$ = 25°C Unless otherwise noted)

	PARAMETER	MIN	ТҮР	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V _F)		1.2	1.4	V	I _F =±20mA
Output	Collector-emitter Breakdown (BV_{CEO})	35			v	I _c =0.1mA
	$Emitter-collector Breakdown (BV_{ECO})$	6			V	$I_{E} = 10 \mu A$
	Collector-emitter Dark Current (I_{CEO})			100	nA	$V_{CE}=20V$
Coupled	Current Transfer Ratio (CTR)	20		400	%	± 1 mAI _F ,5VV _{CE}
	Collector-emitter Saturation Voltage V _{CE(SAT)} Input to Output Isolation Voltage V _{ISO} Input-output Isolation Resistance R _{ISO} Output Rise Time tr Output Fall Time tf	3750 5300 5x10 ¹⁰	4 3	0.2 18 18	V V _{RMS} V _{PK} Ω μs μs	± 20 mA I _F , 1mA I _C See note 1 See note 1 V ₁₀ = 500V (note 1) V _{CE} =2V, I _C =2mA, R _L =100Ω

Note 1 Measured with input leads shorted together and output leads shorted together.